Calibration method	Cross check with simulations	Linear regression	Example of calibrated results	Conclusions
OO	OO	000	OO	00

Calibration of testbeam FEB - B0 results

Dawid Pietruch

AGH University of Krakow, Faculty of Physics and Applied Computer Science

pietruch@agh.edu.pl

17.04.2024

This research was funded by the National Science Centre, Poland, under the grant no. 2021/43/B/ST2/01107

Calibration method	Cross check with simulations	Linear regression	Example of calibrated results	Conclusions
OO	OO	000	00	00

Plan of the presentation

- 1. Method of calibration
- 2. Cross check with Geant4 and simple formula
- 3. Absolute gain after injector calibration
- 4. Example of calibrated results

Calibration method	Cross check with simulations	Linear regression	Example of calibrated results	Conclusions
●O	00	000	00	00

Calibration method

Using a simple single-channel injector, it was possible to inject same charge for each channel.



Fig. 1: Injector circuit

Calibration method ○●	Cross check with simulations OO	Linear regression 000	Example of calibrated results OO	Conclusions 00

Injector calibration

Using an external measurement setup with known gain, it was possible to calibrate our injector. Injector calibration: $Q_{in}[fC] = 0,4628 \cdot U[mV] + 0,5148[fC]$



Fig. 2: Charge in function of generator amplitude - injector calibration



Calibration method	Cross check with simulations	Linear regression	Example of calibrated results	Conclusions
00	●O	000	OO	00

Cross check with simulations

Methods of estimating energy deposition

- Using simple equation for energy loss: $\Delta E(keV) = d (0.1791 + 0.01782 \ln(d))$ with d in um
- Geant4 for 500 μ m



Fig. 4: Energy distribution Geant4 simulation

Fig. 5: Energy loss in function of thickness of Si absorber

Calibration method	Cross check with simulations	Linear regression	Example of calibrated results	Conclusions
00	○●	000	OO	00

Cross check with simulations

Methods of estimating energy deposition

- Using simple equation for energy loss: ΔE(keV) = d (0.1791 + 0.01782 ln(d)) with d in um
- Geant4 for 500 μ m Si

Thanks to MC simulations by Mihai, I was able to calculate the most probable energy deposition in a 500 μ m Si sensor. Assuming 3.6 eV per e-h pair, I calculated the most probable e-h number. The gain was calculated as the Landu MPV using a fit to the raw data divided by the charge.



Calibration method	Cross check with simulations	Linear regression	Example of calibrated results	Conclusions
00	00	●00		00

Linear regression

After calculating MPV for each channel and charge linear regression was applied (4 channels was classified as bad)



Fig. 7: Fit to raw data reconstruction with linear regression applied $(\square) (\square)$

7/13

Calibration method	Cross check with simulations	Linear regression	Example of calibrated results	Conclusions
00	00	○●○	OO	00

Linear regression - gain

From linear regression we can read information about slope and after performing injector calibration we have absolute gain value.



Calibration method	Cross check with simulations	Linear regression	Example of calibrated results	Conclusions
00	OO	00●	OO	00

Linear regression - relative gain

From linear regression we can read information about slope and after normalisation to mean slope value we have relative gain values.



Calibration method	Cross check with simulations	Linear regression	Example of calibrated results	Conclusions
00	OO	000	•O	00

Example of calibrated results Calice

Taking account relative gain for each channel we can perform gain correction for B0 board. As you can see gain difference has no significant influence on MPV position.

15

10

5

15

10

E

Entries

16

16





Fig. 13: Calice corrected MPV position histogram - online reconstruction

18

18

20

20

22

22

LUXE ECAL-r

 $\sigma: 0.5988$

μ: 20.5979 RMSD: 0.6731

24

 σ calib: 0.5116

RMSD: 0.5684

24

MPV [LSB]

u: 20.6052

LUXE ECAL-p

Calibration method	Cross check with simulations	Linear regression	Example of calibrated results	Conclusions
00	OO	000	O•	00

Example of calibrated results Yan

Taking account relative gain for each channel we can perform gain correction for B0 board. As you can see gain difference has no significant influence on MPV position.









Calibration method 00	Cross check with simulations OO	Linear regression 000	Example of calibrated results OO	Conclusions ●O

Conclusions

- Absolute μ_{gain} 3.47 $\left[\frac{LSB}{fC}\right]$ σ 0.0579
- MC simulation agree with laboratory measurements
- Applied gain correction slightly improve MPV distribution



Fig. 16: Absolute gain histogram - fit from raw data



Fig. 17: Calice MPV position histogram - online reconstruction

Calibration method	Cross check with simulations	Linear regression	Example of calibrated results	Conclusions
OO	OO	000	00	O

Thank you for attention